


Infineon IGBT Modules 1200V 50A BSM50GX120DN2

BSM50GX120DN2**Infineon BSM50GX120DN2 General Features**

Manufacturer :	
Part number:	BSM50GX120DN2
Product Catalog :	IGBT Module
Configuration::	3-Phase
Collector- Emitter Voltage VCEO Max: :	1200V
Collector-Emitter Saturation Voltage: :	2.5V
Continuous Collector Current at 25 C : :	78 A
Gate-Emitter Leakage Current: :	200 nA;
Power Dissipation: :	400W;
Maximum Operating Temperature: :	+ 150 C;
Maximum Gate Emitter Voltage: :	20 V
Minimum Operating Temperature: :	- 55 C;
RoHS :	No
Application :	Industrial

Infineon BSM50GX120DN2 Photo

BSM50GX120DN2
Infineon
IGBT Modules 1200V 50A

Infineon BSM50GX120DN2 Supplier info:

Company : **Shunlongwei Electronic Components**
 Contact : **Ms.Alice Peng**
 Tel : **+86 -755 -82732562**
 Email : sales@shunlongwei.com
 Qty Available : 141 pcs

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